

# Super Barrier Rectifier™

Using state-of-the-art SBR IC process technology,  
the following features are made possible in a single device:

### Major ratings and characteristics

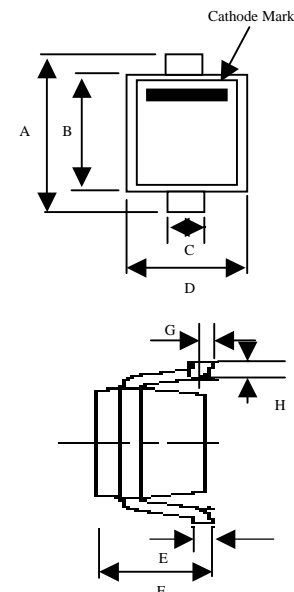
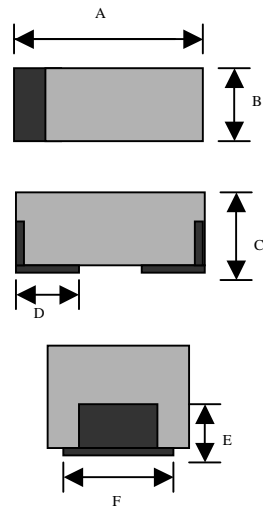
Characteristics	Values	Units
$I_{F(AV)}$ Rectangular Waveform	0.10	A
$V_{RRM}$	20	V
$V_F @ 0.1A, T_J = 75^\circ C$	0.35	V, typ
$T_J$ (operating/storage)	-65 to 125	$^\circ C$

### ELECTRICAL:

- \* Low Forward Voltage Drop
- \* Low Reverse Leakage
- \* Reliable High Temperature Operation
- \* Super Barrier Design
- \* Softest, fast switching capability
- \* 125 $^\circ C$  Operating Junction Temperature

### MECHANICAL:

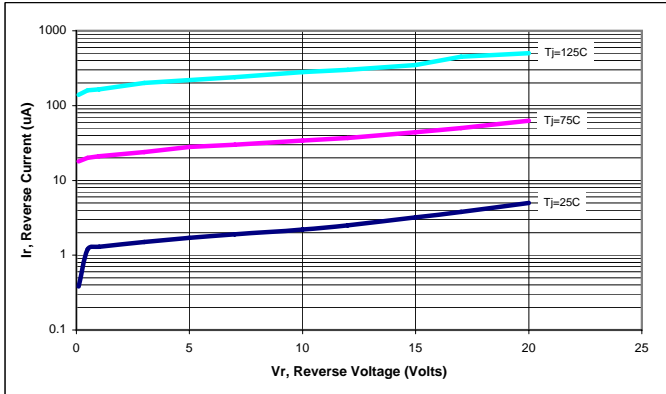
- \* Molded Plastic SOD-323, SOD-523 packages

SBR0120S3	SBR0120S5																																																						
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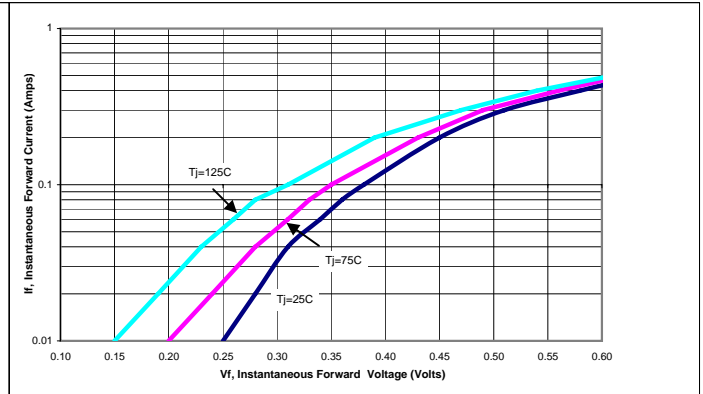
<b>Maximum Ratings and Electrical Characteristics</b> (at 25°C unless otherwise specified)				
	<b>SYMBOL</b>			<b>UNITS</b>
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	$V_{RM}$ $V_{RWM}$ $V_{RRM}$	20		Volts
Average Rectified Forward Current (Rated $V_R$ -20Khz Square Wave)-50% duty cycle	$I_o$	0.10		Amps
Peak Forward Surge Current - 1/2 60hz	$I_{FSM}$	2		Amps
Instantaneous Forward Voltage $I_F = 100mA; T_J = 25^\circ C$ $I_F = 100mA; T_J = 75^\circ C$	$V_F$	Typ --- ---	Max 0.41 0.38	Volts
Maximum Reverse Current at Rated $V_{RM}$ $T_J = 25^\circ C$ $T_J = 75^\circ C$	$I_R^*$	Typ --- ---	Max 20 500	uA uA
Operating and Storage Junction Temperature	$T_J$	-65 to +125		°C

NOTE: Dice are available for customer applications.

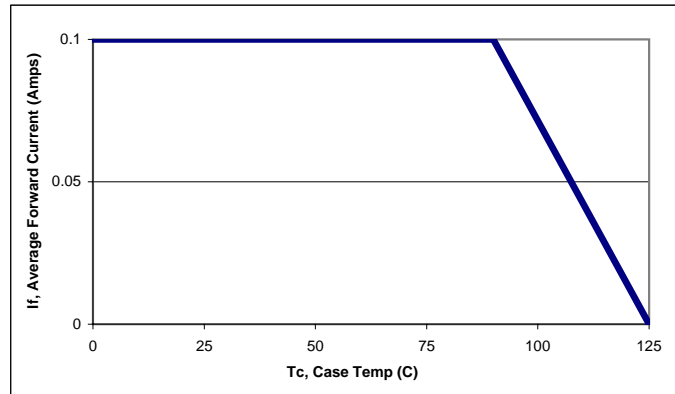
\* Pulse width < 300 uS, Duty cycle < 2%



**Figure 1: Typical Reverse Current**




**Figure 2: Typical Forward Voltage**



**Figure 3: Current Derating, Case**

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